

TECHNICAL DATA
DATA SHEET 4055, REV. C

HERMETIC POWER SCHOTTKY RECTIFIER 175°C Maximum Operation Temperature

DESCRIPTION: A 100-VOLT, 120 AMP, HERMETIC POWER SCHOTTKY RECTIFIER IN A SHD-3/3B PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_c = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_c=100^\circ\text{C}$)	I_o	120	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=10\text{ms}$, Sine)	I_{FSM}	1200	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$)	C_T	3000	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	0.38	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	$^\circ\text{C}$

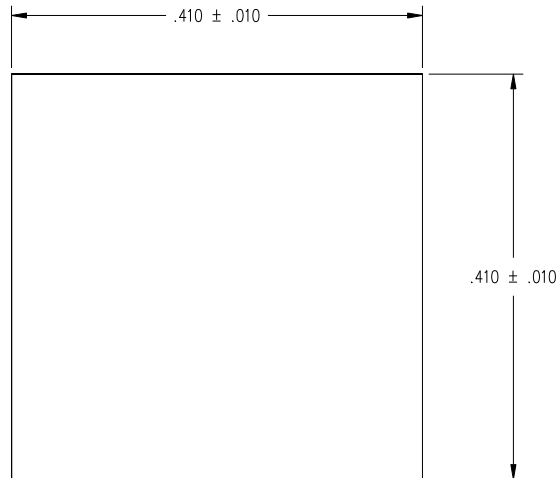
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 40$ Amps) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.71 0.62	Volts
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 120$ Amps) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.90 0.76	Volts
MAXIMUM REVERSE CURRENT (I_r @ 100 V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	2 30	mA

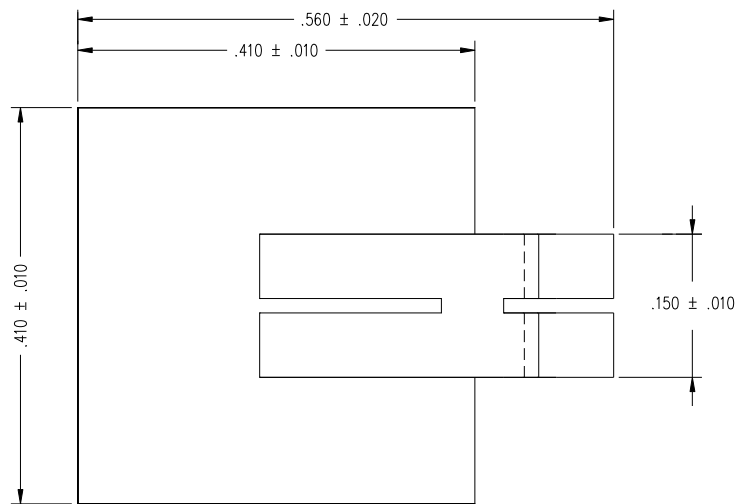
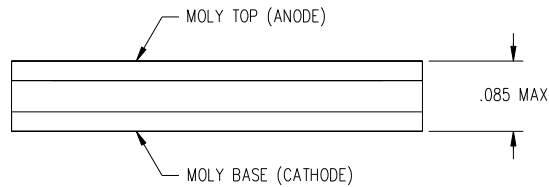
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MECHANICAL DIMENSIONS*: In Inches / mm

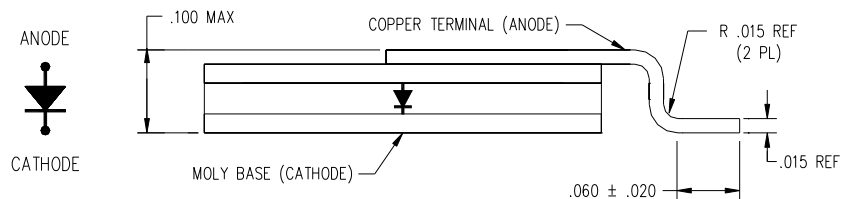
*Dimensions shown are with solder dipping.



SHD-3



SHD-3B



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